



Glass Substrates for RF and Photonics Packaging and Integration

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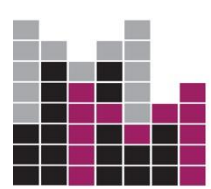
Thomas Budka
RF Diagnostics

Cadence Photonics Summit
November 13, 2019

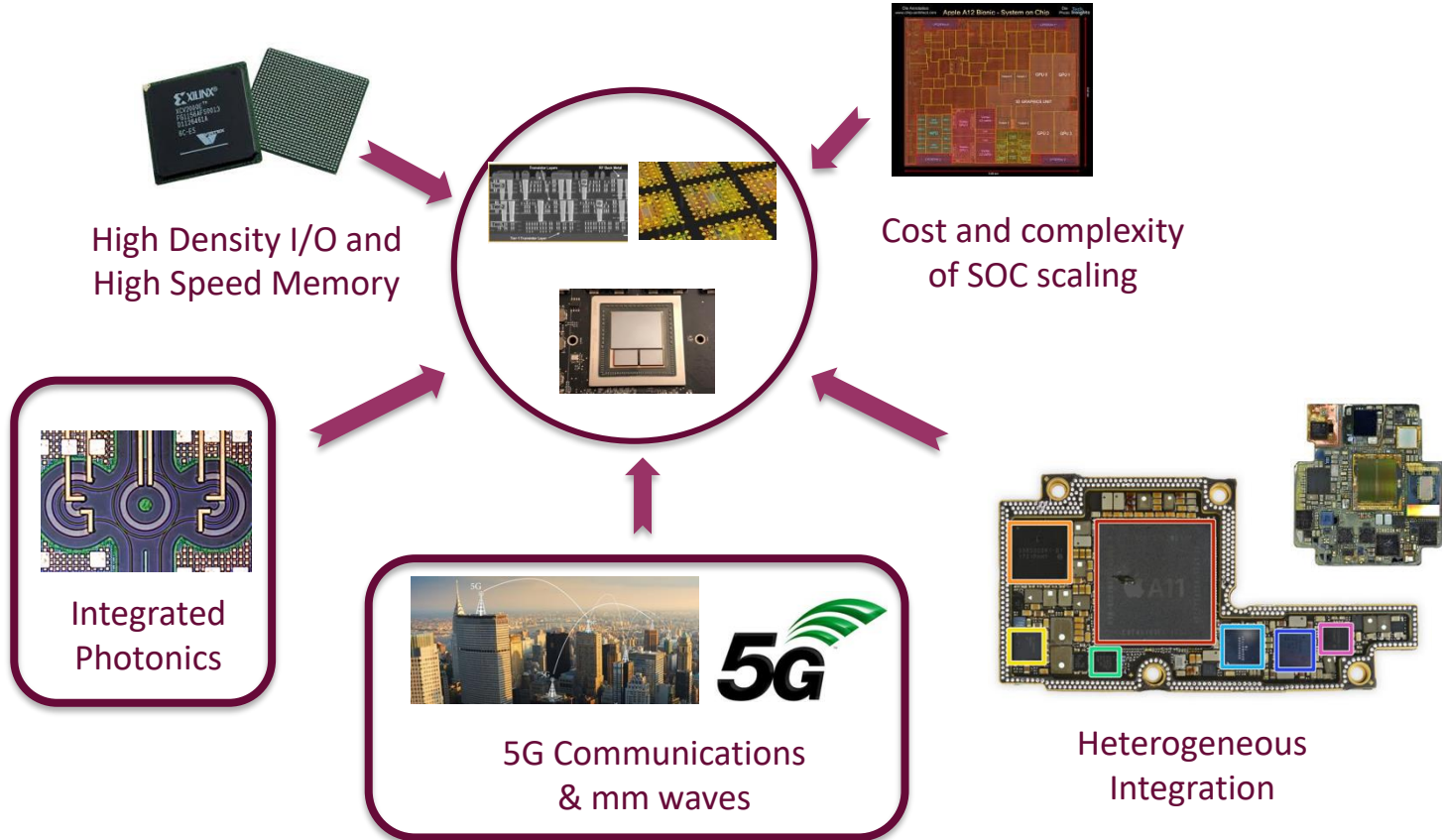


Outline

- Motivations for Advanced Packaging
- The Use of Thin Glass Substrates with Through-Glass Vias (TGV)
- Glass handling solution
- RF Applications
- Photonic Applications
- Thermal Control

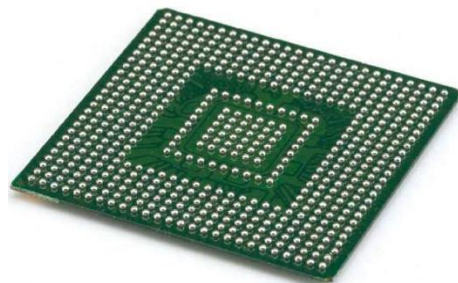


What's Driving Advanced Packaging?

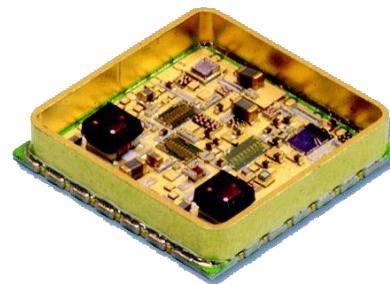




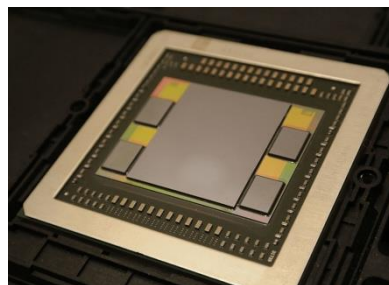
Substrate Materials



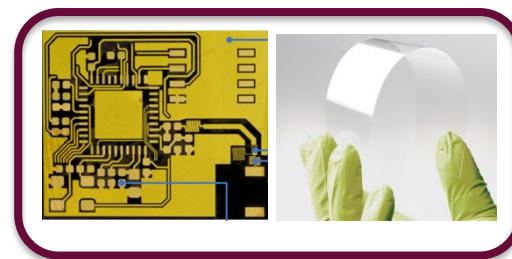
Organic Laminates



Ceramic (thin film,
thick film, HTCC, LTCC)



Silicon



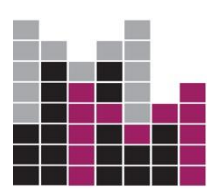
Glass

Glass Has Many Advantages

Characteristic	Ideal Properties	Materials					
		Glass	Si	Poly Si	Organic	Metal	Fused Silica
Electrical	<ul style="list-style-type: none"> High resistivity Low loss and low k 	Good	Poor	Fair	Good	Poor	Good
Physical	<ul style="list-style-type: none"> Smooth surface finish Large area availability Ultra thin 	Good	Fair	Good	Fair	Fair	Good
Thermal	<ul style="list-style-type: none"> High Conductivity 	Fair	Good	Good	Poor	Good	Fair
Mechanical	<ul style="list-style-type: none"> High strength & modulus 	Fair	Fair	Fair	Poor	Good	Fair
Chemical	<ul style="list-style-type: none"> Resistance to process chemicals 	Good	Fair	Fair	Fair	Poor	Good
TPV and RDL	<ul style="list-style-type: none"> Low cost Via formation and fill 	Fair	Poor	Fair	Fair	Poor	Fair
Reliability	<ul style="list-style-type: none"> CTE matched to Si and PWB 	Good	Good	Good	Fair	Poor	Good
Optical	<ul style="list-style-type: none"> Low loss visible and IR, easy fiber attach 	Good	Good	Fair	Poor	Poor	Good
Cost	<ul style="list-style-type: none"> Low raw material and processing costs 	Good	Poor	Fair	Good	Good	Good

■ Good
 ■ Fair
 ■ Poor

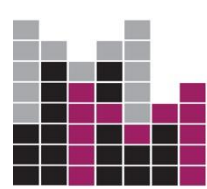
- ✓ Low dielectric constant and loss tangent through 100 GHz
- ✓ Dimensional stability – precise features
- ✓ Drawn in large sheets (1m x 500m) – low cost panel processing possible
- ✓ Can be drawn 100 μm thick – no grinding necessary
- ✓ Smooth surface (< 1 nm rms)
- ✓ CTE match to Si
- ✓ Inert, no moisture absorption
- ✓ Optical properties, fiber attach, waveguides
- Reduced SWaP-C



Technologies and Markets for Glass Interposers

	RF	Optics & Photonics	Digital Interposer	MEMS & Sensors
Wireless Comms.	✓	✓	✓	✓
Datacom and HPC	✓	✓	✓	
Defense	✓	✓	✓	✓
Medical	✓	✓		✓
IoT	✓			✓
Consumer	✓	✓	✓	✓

Desirable RF and photonic properties make glass a promising choice for RF photonics



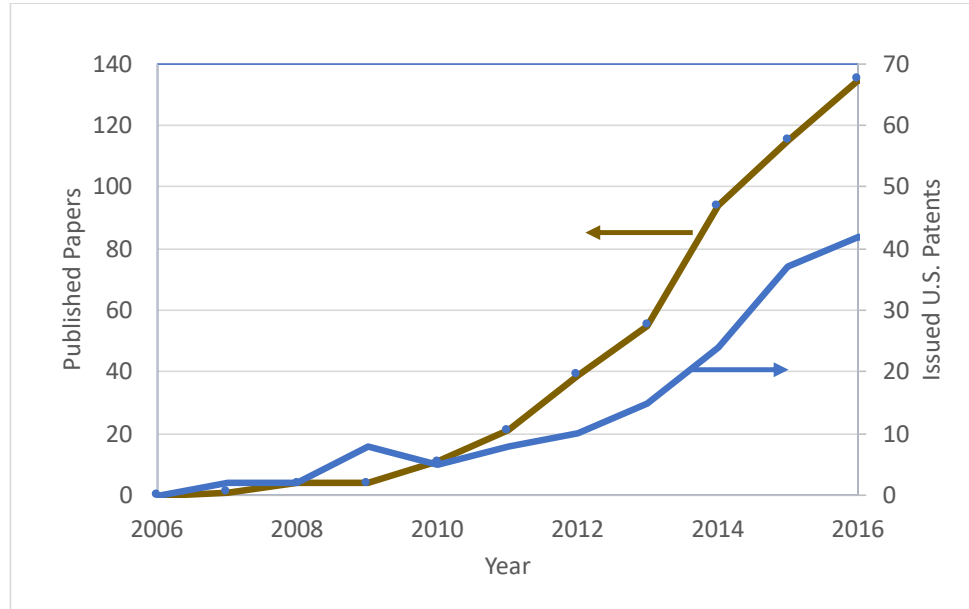
Increasing Interest in Glass

Companies

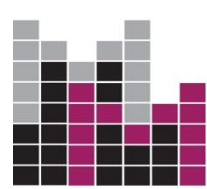
Corning
Asahi Glass Corp.
Schott
Mosaic Microsystems
Qualcomm
GE
Global Foundries
IBM
ST Micro
ASE
TSMC
Marvell
Samtec
Menlo Micro

Research Institutes

GA Tech
Univ. of Florida
Univ. of Rochester
McGill
Fraunhofer
IMEC



Published papers by Google Scholar and Patents by USTPO. Searches for “glass interposers”



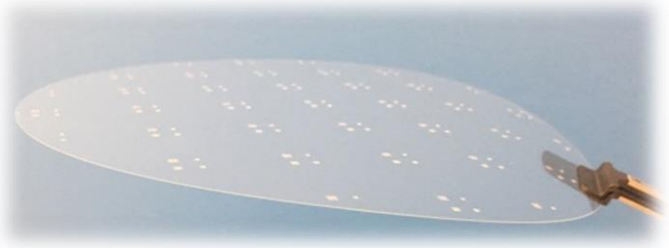
Glass Wafer Handling Challenges and Solution

The Challenge:

Immature supply chain

Thin glass with through-holes has challenges:

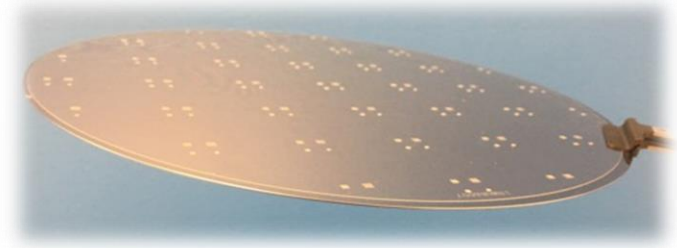
- Excess sag
- Transparent to robotic sensing
- Breakage
- Concern over contamination



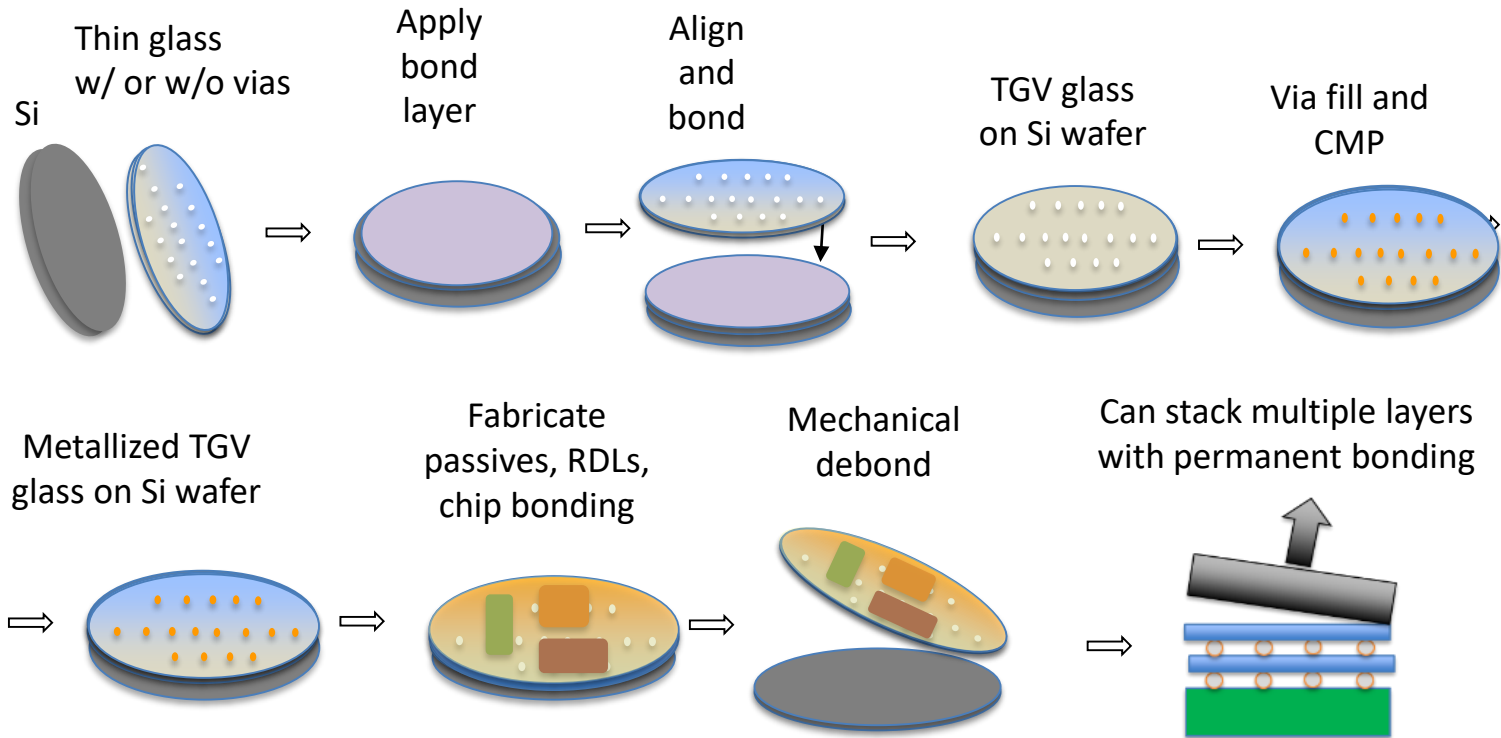
The Solution:

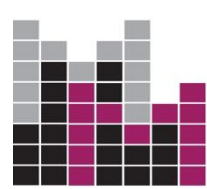
Thin glass with TGVs temporarily bonded to silicon carrier wafer

- Inorganic bond stable up to 400C
- No outgassing
- Simple mechanical de-bond
- Compatible with existing semiconductor processing and automation equipment



Wafer Handling and Processing Technology



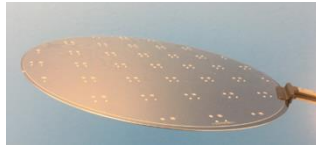


Mosaic's Products: Bonded Glass Wafers



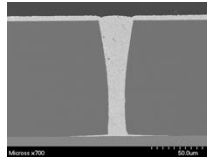
Thin glass on Carrier

Glass thickness 100 μm - 300 μm



Glass with custom through-glass holes

Hole diameter $\leq 35 \mu\text{m}$



Fully or conformally filled vias

Filled vias w/ CMP

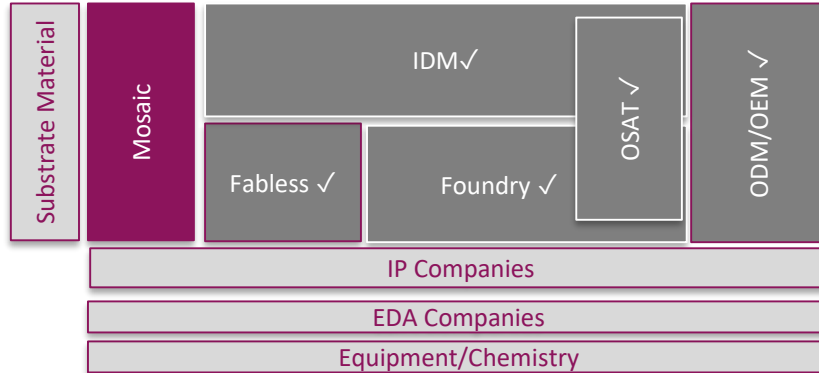


Thin glass with custom structures and devices

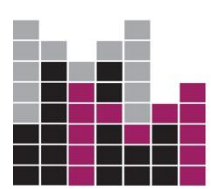
Metallized wafer



Supply Chain



- Mosaic serves companies across the electronics supply chain.
- Some companies will buy direct while others will influence or specify the technology.
- The type of product we provide depends on the application and type of customer.



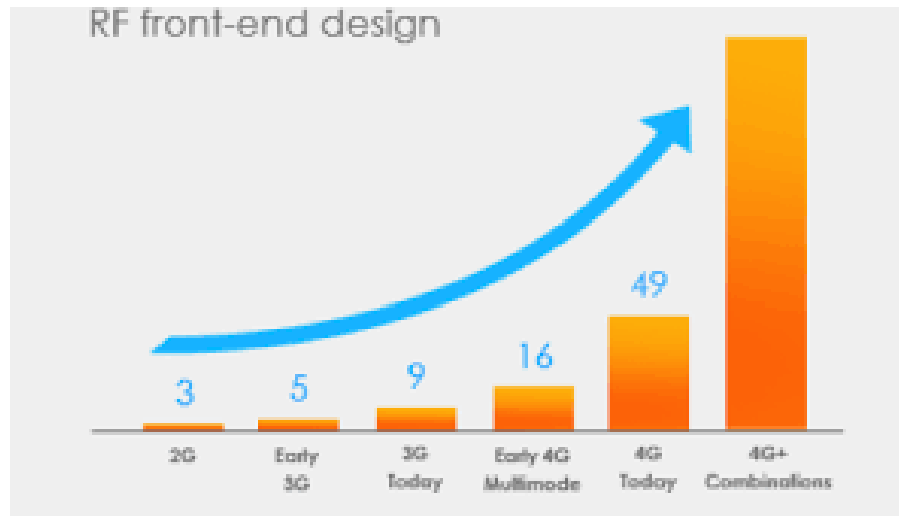
RF Applications of Glass



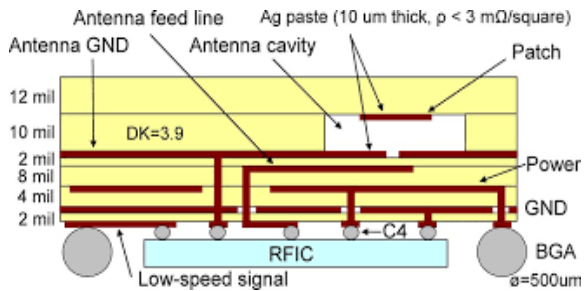
Increasing Complexity of RF Systems is Driving New Packaging Technology

- RF front ends for user equipment and infrastructure getting more complex
- Multi-bands, multi-carrier, multi-standards, and MIMO, along with WiFi, BT, and GPS
- 5G will make things even more complicated with both sub 6 GHz and mm waves.
 - 28 – 80 GHz and 2 – 10 Gbps
- Mm Waves will require beam forming and steering – so phased arrays.

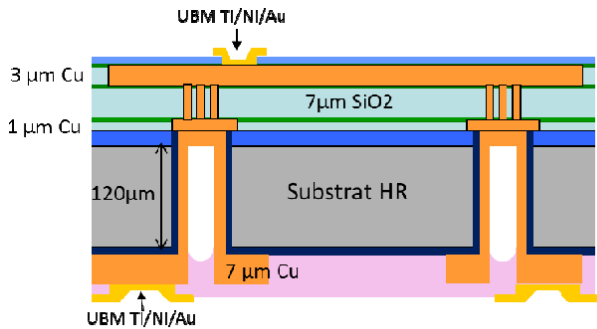
80+ Filters in LTE and 5G Phones



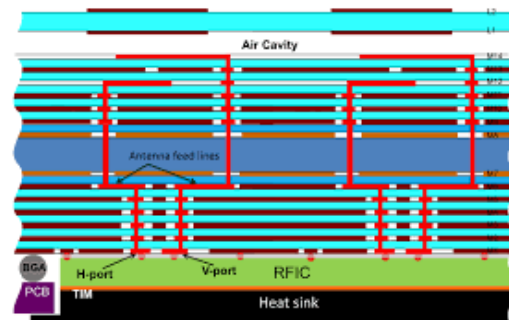
Millimeter Wave Packaging Substrate Materials



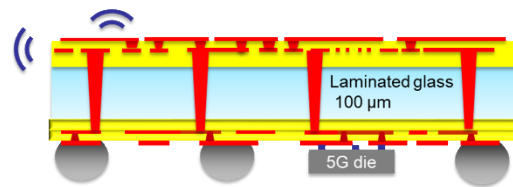
Ceramic (IBM)



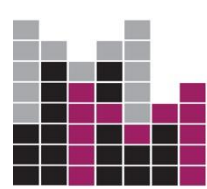
HR Silicon (LETI)



Organic (IBM)

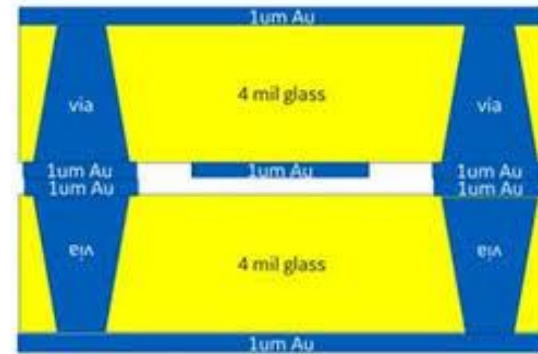


Glass with Organic Buildup (GA Tech)



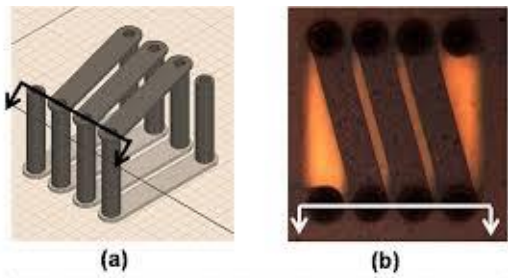
All Inorganic Package with Glass

- Multiple layers possible with thermo-compression bonding
- Au microstrip, CPWG, and Stripline
- CPWG loss < 0.4 dB/mm @ 30 GHz
- High isolation between transmission lines
- Ta resistors
- MIM capacitors
- Can be used to make a variety of mm wave devices including True Time Delay modules

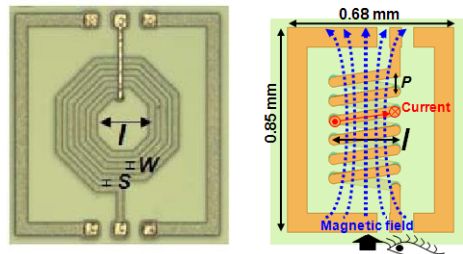


All Glass (GE)

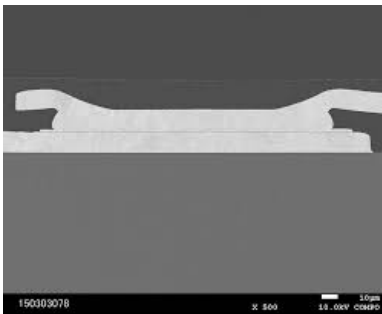
Thin Film Passives on Glass



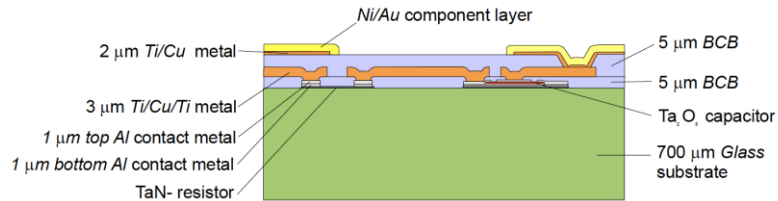
3D Helical Inductors
(Corning and Qualcomm)



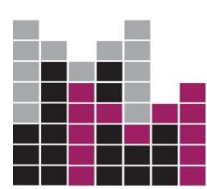
Helical inductors on glass with TGV give
45% reduction in area vs. spiral (TSMC)



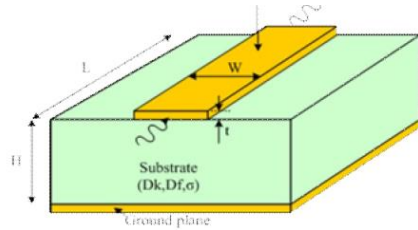
MIM Capacitor with SiN dielectric
(Corning and Qualcomm)



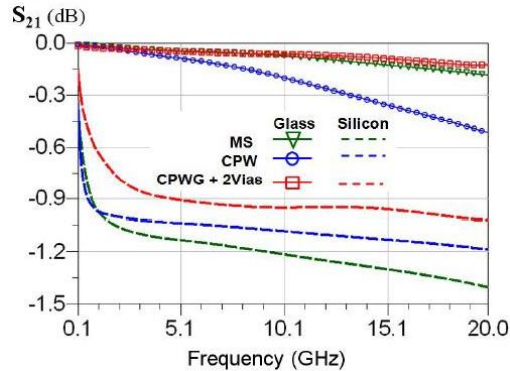
Ta and TaN thin film resistors (IMEC)



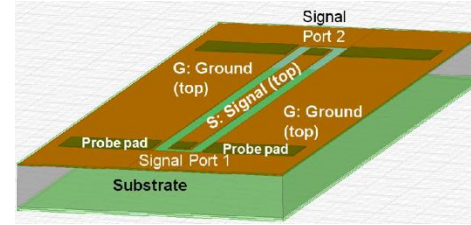
Transmission Lines on Glass



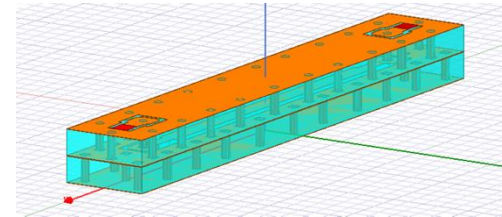
Microstrip (Corning, Qualcomm, and Dai Nippon Screen)



Glass vs. Si Performance Comparison (ITRI and Corning)

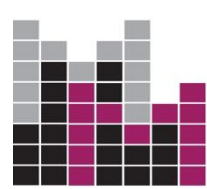


CPW (ITRI and Corning)



Stripline with TGV Array (GE and Mosaic)

Less than 0.1 dB/mm loss for CPWG @ 10 GHz



GE and Mosaic Capabilities and Design Rules*

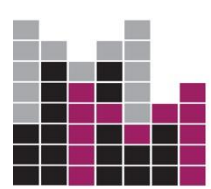
TGV Glass (Mosaic)

Materials	Borosilicate Glass, Fused Silica
Substrate Diameter	100, 150, 200 mm, may add 300mm
Thickness	100 um – 200 um, will add 300 um
Surface Roughness	< 1 nm
Via Diameter max	35 um
Via diameter min	10 um
Via sidewall slope	2 degrees
Via pitch	< 150um now, going to 2X diameter

Packaging (GE)

Layers of Glass	
Metals	Available from GE upon request
Catch Pad Diameter	
Metal Thickness	
Line width	
Line spacing	
Capacitor material	
Capacitance/mm ²	
Resistors	
Wafer diameter	

* RF Diagnostics has experience in designing mm wave packages with TGV glass



Photonic Applications of Glass



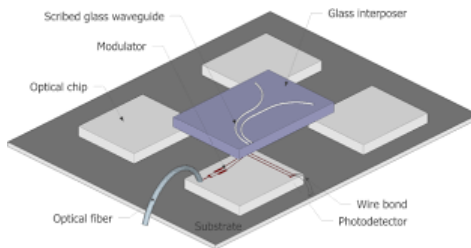
Si vs. Glass Interposers for Photonics

- Si most common substrate for photonic interposers
- Advantages of Si
 - Can be used for an active or passive interposer
 - Uses the same process technology as is used for SIP die
- Capabilities of Glass:
 - Transparent to wavelengths of interest
 - Can incorporate waveguides, either deposited or laser written
 - Can provide passive fiber attach solution
 - Better choice for RF photonics due to superior RF properties
 - Lower cost than Si

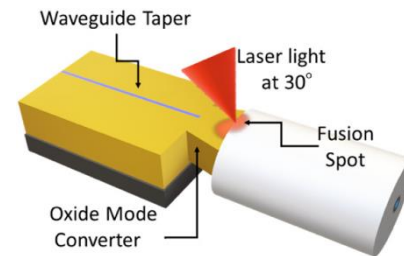
Laser Writing of Optical Waveguides in Glass



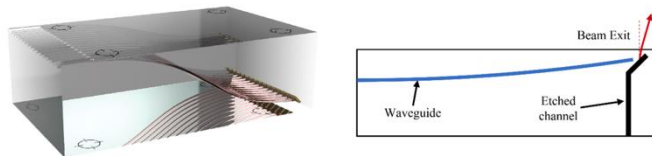
- McGill
- Optoscribe
- Harvard
- STMicro
- Corning
- IMRA
- SUNY Binghamton
- NIAIST (Japan)



Waveguides can be written at any depth → after PIC attach. (McGill)

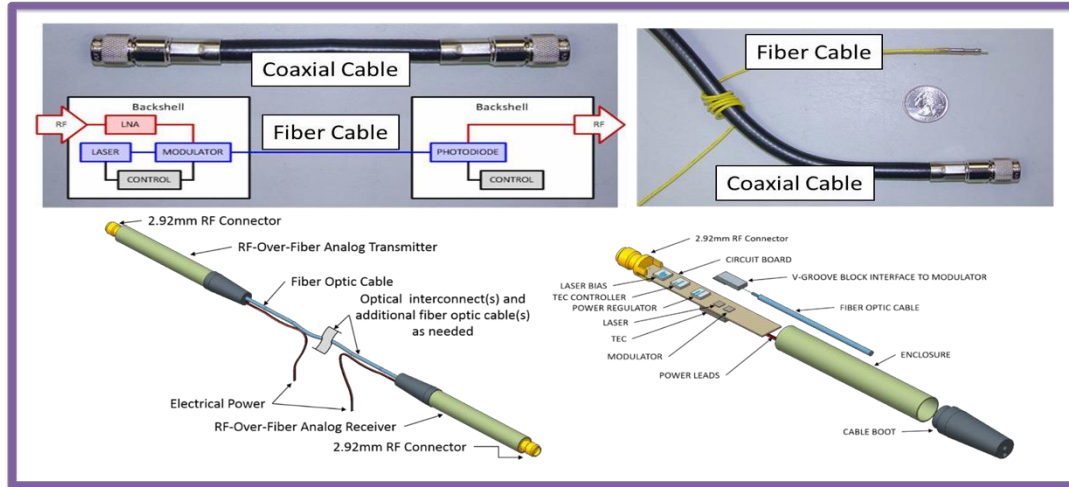


Direct welding of fiber to glass
(University of Rochester)

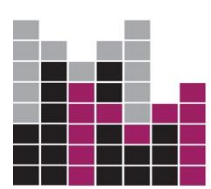


Low Loss, 0.2 dB/cm (Optoscribe)

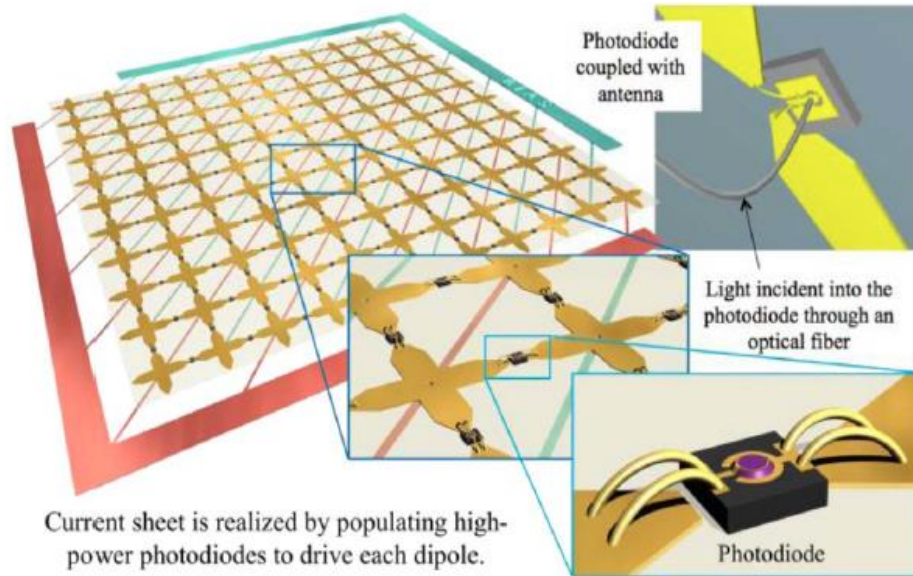
Potential Application: RF over Fiber



Class could be used as the substrate for this type of device.

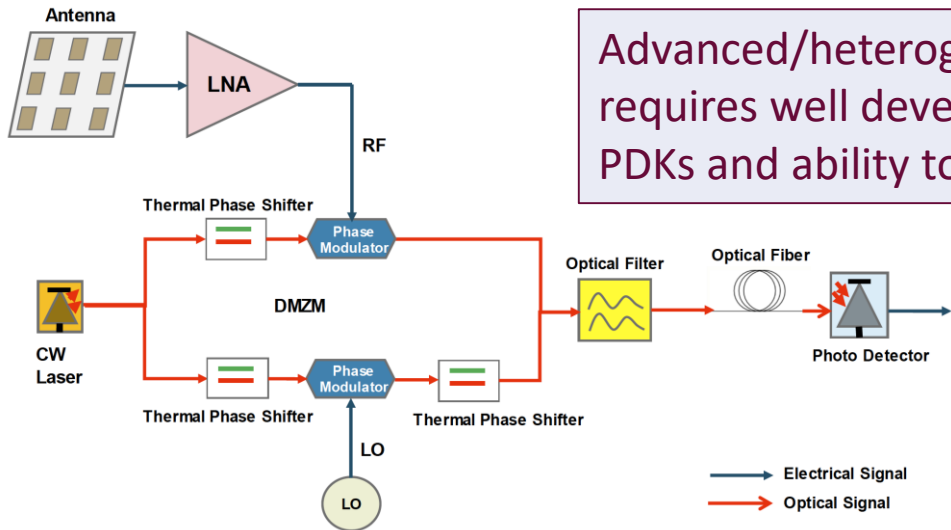


Potential Application: Photonic mm Wave Array Using Photodiodes

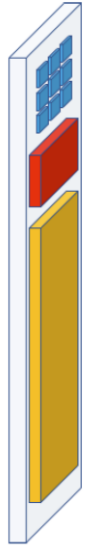






Cadence Photonics Summit Design Example



Advanced/heterogeneous integration requires well developed packaging PDKs and ability to co-design

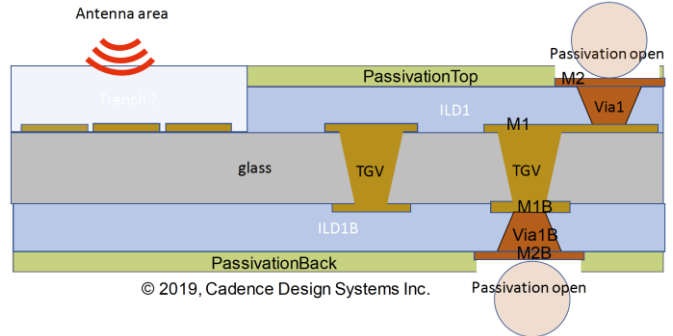


Legend



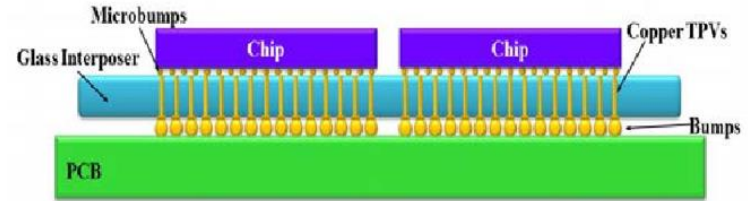
-  Antenna Array
-  LNA (RF E-chip)
-  PIC (active Interposer)
-  Substrate (Glass interposer)

 Electrical Signal
 Optical Signal

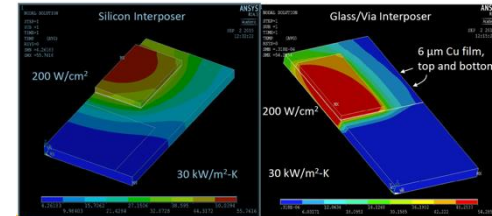


Thermal Control with Cu Vias

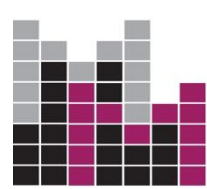
- K for glass = 1 W/m-K
- K for Si = 130 W/m-K
- K for Cu = 384 W/m-K
- Thermal effects with glass can be mitigated by using heat spreaders and thermal vias
- Low K can work to your advantage when you need to thermally isolate die.
- Need to model EM effects of thermal vias



GA Tech



University of Maryland



Summary

- Advanced packaging required advances in substrate materials
- Glass is a promising new material due to electrical, mechanical, and optical properties
- Challenges of weak supply chain and difficulty in handling thin glass are being addressed
- Desirable RF and photonic properties make gall attractive for mm wave and RF over fiber applications
- Low thermal conductivity must be taken into account and can be used to an advantage.
- Development of PDKs for glass packaging is a key part of the supply chain.



Thank You

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